

### BC856/BC857/BC858 SOT-23 Plastic-Encapsulate Transistors (PNP)

### **General description**

SOT-23 Plastic-Encapsulate Transistors (PNP)

#### **FEATURES**

- Complementary to BC846/BC847/BC848
- Power Dissipation of 200mW
- Ideally suited for automatic insertion
- For switching and AF amplifier applications
- SOT-23 Small Outline Plastic Package
- Epoxy UL: 94V-0
- Mounting Position: Any



#### **DEVICE MARKING CODE:**

BC856A=3A	BC856B=3B	
BC857A=3E	BC857B=3F	BC857C=3G
BC858A=3J	BC858B=3K	BC858C=3L

### Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

Parameters	Symbols		Value	Unit
Collector-Base Voltage	Vсво	BC856	-80	
		BC857	-50	V
		BC858	-30	
Collector-Emitter Voltage	VCEO	BC856	-65	
		BC857	-45	V
		BC858	-30	
Emitter -Base Voltage	VEBO		-6	V
Collector Current-Continuous	Ic		-100	mA
Collector Power Dissipation	Pc		200	mW
Junction Temperature	Tj		150	${\mathbb C}$
Storage Temperature	Tstg		-55-+150	${\mathbb C}$
Thermal resistance From junction to ambient	Reja		625	°C/W

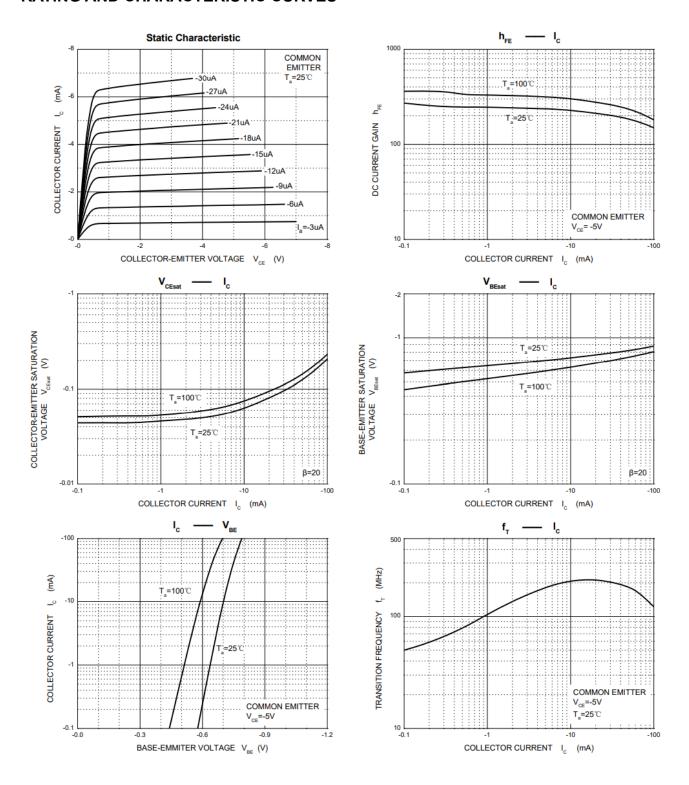


Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

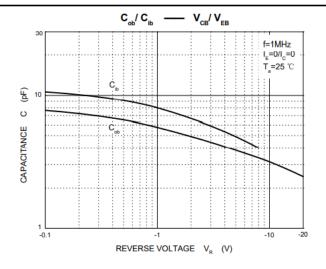
Parameter	Symbols	Test Condition		Limits		Unit
Farameter	Symbols			Min	Max	Jill
Collector-base breakdown voltage	V(BR)CBO	IC=-10uA, IE=0	BC856 BC857 BC858	-80 -50 -30		V
Collector-emitter breakdown voltage	V(BR)CEO	IC=-10mA, IB=0	BC856 BC857	-65 -45		V
			BC858	-30		
Emitter-base breakdown voltage	V(BR)EBO	IE=10uA, IC=0		-6		V
Collector cut-off current	Ісво	VCB=-70V, IE=0 VCB=-45V, IE=0 VCB=-25V, IE=0	BC856 BC857 BC858		-100	nA
Collector cut-off current	ICEO	VCE=-60V, IB=0 VCE=-40V, IB=0 VCE=-25V, IB=0	BC856 BC857 BC858		-100	nA
Emitter cut-off current	IEBO	VEB=-5V, IC=0			-100	nA
DC current gain	hFE	BC856A;BC857A;BC858A VCE=-5V, IC=-2mA BC856B;BC857B;BC858B BC857C;BC858C		125 220 420	250 475 800	
Collector-emitter saturation voltage	VCE(sat)	IC=-100mA, IB=-5mA			-0.50	V
Base -emitter saturation voltage	VBE(sat)	IC=-100mA, IB=-5mA			-1.10	V
Transition frequency	fτ	VCE=-5V, IC=-10mA,f=100MHz		100		MHz
Collector output capacitance	Cob	VCB=-10V, f=1MHz			4.5	pF

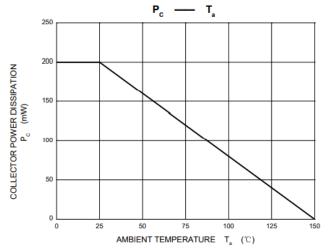


### RATING AND CHARACTERISTIC CURVES

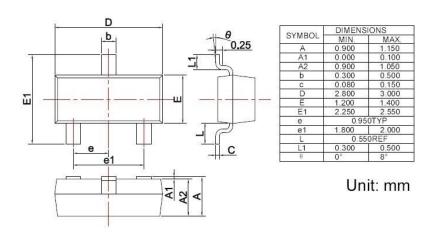






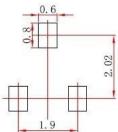


#### SOT-23 PACKAGE OUTLINE Plastic surface mounted package



Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



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